THERMAL DATA

R _{thj-case} Thermal Resistance Junction-case	Max	3.8	°C/W
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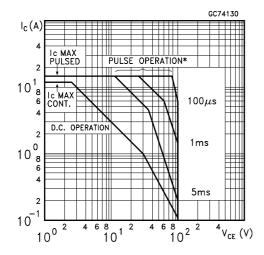
ELECTRICAL CHARACTERISTICS ($T_{case} = 25 \,^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _{СВО}	Collector Cut-off Current (I _E = 0)	V _{CB} = 100 V V _{CB} = 100 V	T _{case} = 150 ^o C			100 5	μA mA
I _{CEO}	Collector Cut-off Current ($I_B = 0$)	V _{CE} = 80 V				1	mA
I _{EBO}	Emitter Cut-off Current $(I_C = 0)$	$V_{EB} = 5 V$				2	mA
$V_{CEO(sus)^*}$	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 100 mA		100			V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	Ic = 5 A Ic = 10 A	I _B = 20 mA I _B = 100 mA			2 3	V V
V _{BE(sat)} *	Base-Emitter Saturation Voltage	Ic = 5 A Ic = 10 A	I _B = 20 mA I _B = 100 mA			2.5 4	V V
h _{FE} *	DC Current Gain	$I_{C} = 3 A$ $I_{C} = 5 A$ $I_{C} = 10 A$	V _{CE} = 3 V V _{CE} = 3 V V _{CE} = 3 V	1000 750 100		20000	
V _F *	Parallel-diode Forward Voltage	I _F = 5 A I _F = 10 A			1.3 1.8	2 4	V V
h _{fe}	Small Signal Current Gain	I _C = 1 A f = 1 MHz	V _{CE} = 10 V	20			

* Pulsed: Pulse duration = 300 μ s, duty cycle 1.5 %

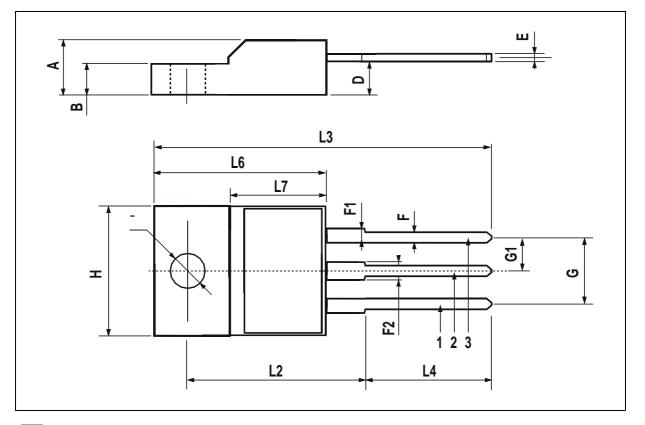
For PNP types voltage and current values are negative.

Safe Operating Area



DIM.	mm			inch			
DINI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	4.4		4.6	0.173		0.181	
В	2.5		2.7	0.098		0.106	
D	2.5		2.75	0.098		0.108	
E	0.45		0.7	0.017		0.027	
F	0.75		1	0.030		0.039	
F1	1.15		1.7	0.045		0.067	
F2	1.15		1.7	0.045		0.067	
G	4.95		5.2	0.195		0.204	
G1	2.4		2.7	0.094		0.106	
Н	10		10.4	0.393		0.409	
L2		16			0.630		
L3	28.6		30.6	1.126		1.204	
L4	9.8		10.6	0.385		0.417	
L6	15.9		16.4	0.626		0.645	
L7	9		9.3	0.354		0.366	
Ø	3		3.2	0.118		0.126	

TO-220FP MECHANICAL DATA



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